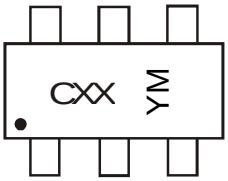
Marking Information

SOT363



CXX = Product Type Marking Code
YM = Date Code Marking
Y = Year (ex: F = 2018)
M = Month (ex: 9 = September)

Date Code Key

Year	2018	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028
Code	F	G	H	I	J	K	L	M	N	O	P

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Absolute Maximum Ratings NPN Section (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Supply Voltage <Pin: (6) to (1)>		V_{CC}	50	V
Input Voltage <Pin: (2) to (1)>	DCX124EU	V_{IN}	-10 to +40	V
	DCX144EU		-10 to +40	
	DCX114YU		-6 to +40	
	DCX123JU		-5 to +12	
	DCX114EU		-10 to +40	
	DCX143TU		-5V Max	
	DCX143EU		-10 to +30	
	DCX114TU		-5V Max	
	DCX143ZU		-10 to +30	
	DCX115EU		-10 to +40	
Output Current	DCX124EU	I_O	30	mA
	DCX144EU		30	
	DCX114YU		70	
	DCX123JU		100	
	DCX114EU		50	
	DCX143TU		100	
	DCX143EU		100	
	DCX114TU		100	
	DCX143ZU		100	
	DCX115EU		20	
Output Current		I_C (Max)	100	mA

Absolute Maximum Ratings PNP Section (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Supply Voltage <Pin: (4) to (3)>		V_{CC}	50	V
Input Voltage <Pin: (5) to (4)>	DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143TU DCX143EU DCX114TU DCX143ZU DCX115EU	V_{IN}	+10 to -40 +10 to -40 +6 to -40 +5 to -12 +10 to -40 +5V Max +10 to -30 +5V Max +5 to -30 +10 to -40	V
Output Current	DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143TU DCX143EU DCX114TU DCX143ZU DCX115EU	I_O	-30 -30 -70 -100 -50 -100 -100 -100 -100 -20	mA
Output Current		I_C (Max)	-100	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Notes 7 & 8)	P_D	200	mW
Thermal Resistance, Junction to Ambient Air (Note 7)	$R_{\theta JA}$	625	°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

Notes: 7. Mounted on FR-4 PC Board with minimum recommended pad layout.
8. 150mW per element must not be exceeded.

Electrical Characteristics NPN Section (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
R1 Only (DCX143TU & DCX114TU)							
Collector-Base Breakdown Voltage		BV_{CBO}	50	—	—	V	I_C = 50μA
Collector-Emitter Breakdown Voltage		BV_{CEO}	50	—	—	V	I_C = 1mA
Emitter-Base Breakdown Voltage		BV_{EBO}	5	—	––	V	I_E = 50μA
Collector Cutoff Current		I_{CBO}	—	—	0.5	μA	V_{CB} = 50V
Emitter Cutoff Current		I_{EBO}	—	—	0.5	μA	V_{EB} = 4V
Collector-Emitter Saturation Voltage		$V_{CE(SAT)}$	—	—	0.3	V	I_C/I_B = 2.5mA / 0.25mA DCX143TU I_C/I_B = 1mA / 0.1mA DCX114TU
DC Current Transfer Ratio		h_{FE}	100	250	600	—	I_C = 1mA, V_{CE} = 5V
Input Resistor (R_1) Tolerance		ΔR_1	-30	—	+30	%	—
Gain-Bandwidth Product		f_T	—	250	—	MHz	V_{CE} = 10V, I_E = -5mA, f = 100MHz
R1/R2 Only							
Input Voltage	DCX124EU	$V_{I(oFF)}$	0.5	1.1	—	V	V_{CC} = 5V, I_O = 100μA
	DCX144EU		0.5	1.1			
	DCX114YU		0.3	—			
	DCX123JU		0.5	—			
	DCX114EU		0.5	1.1			
	DCX143EU		0.5	1.16			
	DCX143ZU		0.5	—			
	DCX115EU		0.5	—			
	DCX124EU	$V_{I(ON)}$	—	1.9	3.0		V_O = 0.3V, I_O = 5mA
	DCX144EU			1.9	3.0		V_O = 0.3V, I_O = 2mA
	DCX114YU			—	1.4		V_O = 0.3V, I_O = 1mA
	DCX123JU			—	1.1		V_O = 0.3V, I_O = 5mA
	DCX114EU			1.9	3.0		V_O = 0.3V, I_O = 10mA
	DCX143EU			1.99	3.0		V_O = 0.3V, I_O = 20mA
	DCX143ZU			—	1.3		V_O = 0.3V, I_O = 5mA
	DCX115EU			—	3		V_O = 0.3V, I_O = 1mA
Output Voltage	DCX124EU	$V_{O(ON)}$	—	0.1	0.3	V	I_O/I_I = 10mA / 0.5mA
	DCX144EU						I_O/I_I = 10mA / 0.5mA
	DCX114YU						I_O/I_I = 5mA / 0.25mA
	DCX123JU						I_O/I_I = 5mA / 0.25mA
	DCX114EU						I_O/I_I = 10mA / 0.5mA
	DCX143EU						I_O/I_I = 10mA / 0.5mA
	DCX143ZU						I_O/I_I = 5mA / 0.25mA
	DCX115EU						I_O/I_I = 10mA / 0.5mA
Input Current	DCX124EU	I_I	—	—	0.36	mA	V_I = 5V
	DCX144EU				0.18		
	DCX114YU				0.88		
	DCX123JU				3.6		
	DCX114EU				0.88		
	DCX143EU				0.88		
	DCX143ZU				1.8		
	DCX115EU				0.15		
Output Current		$I_{O(OFF)}$	—	—	0.5	μA	V_{CC} = 50V, V_I = 0V
DC Current Gain	DCX124EU	G_I	56	—	—	—	V_O = 5V, I_O = 5mA
	DCX124EUQ		60				V_O = 5V, I_O = 5mA
	DCX144EU		68				V_O = 5V, I_O = 5mA
	DCX114YU		68				V_O = 5V, I_O = 10mA
	DCX114YUQ		80				V_O = 5V, I_O = 10mA
	DCX123JU		80				V_O = 5V, I_O = 10mA
	DCX114EU		30				V_O = 5V, I_O = 5mA
	DCX143EU		50				V_O = 5V, I_O = 10mA
	DCX143ZU		80				V_O = 5V, I_O = 10mA
	DCX115EU		82				V_O = 5V, I_O = 5mA
Input Resistor (R_1) Tolerance		ΔR_1	-30	—	+30	%	—
Resistance Ratio Tolerance		$\Delta R_2/R_1$	-20	—	+20	%	—
Gain-Bandwidth Product		f_T	—	250	—	MHz	V_{CE} = 10V, I_E = 5mA, f = 100MHz

Electrical Characteristics PNP Section (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
R1 Only (DCX143TU & DCX114TU)							
Collector-Base Breakdown Voltage		BV_{CBO}	-50	—	—	V	I_C = -50µA
Collector-Emitter Breakdown Voltage		BV_{CEO}	-50	—	—	V	I_C = -1mA
Emitter-Base Breakdown Voltage		BV_{EBO}	-5	—	—	V	I_E = -50µA
Collector Cutoff Current		I_{CBO}	—	—	-0.5	µA	V_{CB} = -50V
Emitter Cutoff Current		I_{EBO}	—	—	-0.5	µA	V_{EB} = -4V
Collector-Emitter Saturation Voltage		$V_{CE(SAT)}$	—	—	-0.3	V	I_C/I_B = 2.5mA / 0.25mA DCX143TU I_C/I_B = 1mA / 0.1mA DCX114TU
DC Current Transfer Ratio		h_{FE}	100	250	600	—	I_C = -1mA, V_{CE} = -5V
Input Resistor (R_1) Tolerance		ΔR_1	-30	—	+30	%	—
Gain-Bandwidth Product		f_T	—	250	—	MHz	V_{CE} = -10V, I_E = 5mA, f = 100MHz
R1/R2 Only							
Input Voltage	DCX124EU	$V_{I(OFF)}$	-0.5	-1.1	—	V	V_{CC} = -5V, I_O = -100µA
	DCX144EU		-0.5	-1.1			
	DCX114YU		-0.3	—			
	DCX123JU		-0.5	—			
	DCX114EU		-0.5	-1.1			
	DCX143EU		-0.5	-1.16			
	DCX143ZU		-0.5	—			
	DCX115EU		-0.5	—			
	DCX124EU	$V_{I(ON)}$	—	-1.9	-3.0		V_O = -0.3V, I_O = -5mA
	DCX144EU			-1.9	-3.0		V_O = -0.3V, I_O = -2mA
	DCX114YU			—	-1.4		V_O = -0.3V, I_O = -1mA
	DCX123JU			—	-1.1		V_O = -0.3V, I_O = -5mA
	DCX114EU			-1.9	-3.0		V_O = -0.3V, I_O = -10mA
	DCX143EU			-2.5	-3.0		V_O = -0.3V, I_O = -20mA
	DCX143ZU			—	-1.3		V_O = -0.3V, I_O = -5mA
	DCX115EU			—	-3		V_O = -0.3V, I_O = -1mA
Output Voltage	DCX124EU	$V_{O(ON)}$	—	-0.1	-0.3	V	I_O/I_I = -10mA / -0.5mA
	DCX144EU						I_O/I_I = -10mA / -0.5mA
	DCX114YU						I_O/I_I = -5mA / -0.25mA
	DCX123JU						I_O/I_I = -5mA / -0.25mA
	DCX114EU						I_O/I_I = -10mA / -0.5mA
	DCX143EU						I_O/I_I = -10mA / -0.5mA
	DCX143ZU						I_O/I_I = -5mA / -0.25mA
	DCX115EU						I_O/I_I = -10mA / -0.5mA
Input Current	DCX124EU	I_I	—	—	-0.36	mA	V_I = -5V
	DCX144EU				-0.18		
	DCX114YU				-0.88		
	DCX123JU				-3.6		
	DCX114EU				-0.88		
	DCX143EU				-0.88		
	DCX143ZU				-1.8		
	DCX115EU				-0.15		
Output Current		$I_{O(OFF)}$	—	—	-0.5	µA	V_{CC} = 50V, V_I = 0V
DC Current Gain	DCX124EU	G_I	56	—	—	—	V_O = -5V, I_O = -5mA
	DCX124EUQ		60				V_O = -5V, I_O = -5mA
	DCX144EU		68				V_O = -5V, I_O = -5mA
	DCX114YU		68				V_O = -5V, I_O = -10mA
	DCX114YUQ		80				V_O = -5V, I_O = -10mA
	DCX123JU		80				V_O = -5V, I_O = -10mA
	DCX114EU		30				V_O = -5V, I_O = -5mA
	DCX143EU		40				V_O = -5V, I_O = -10mA
	DCX143ZU		80				V_O = -5V, I_O = -10mA
	DCX115EU		82				V_O = -5V, I_O = -5mA
Input Resistor (R_1) Tolerance		ΔR_1	-30	—	+30	%	—
Resistance Ratio Tolerance		$\Delta R_2/R_1$	-20	—	+20	%	—
Gain-Bandwidth Product		f_T	—	250	—	MHz	V_{CE} = -10V, I_E = -5mA, f = 100MHz

Typical Curves – Total Device

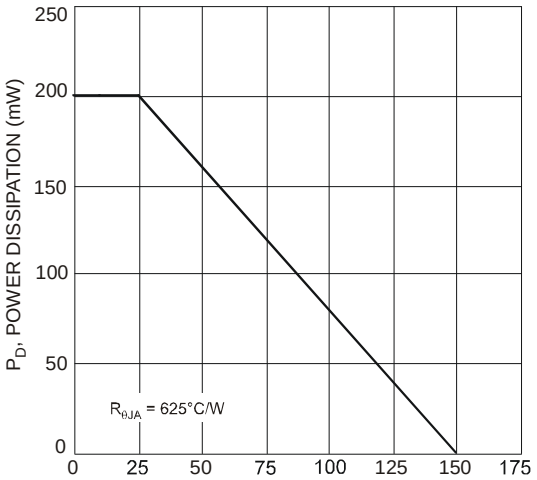


Fig. 1 Power Derating Curve

Typical Curves – DCX123JU PNP Section (@T_A = +25°C, unless otherwise specified.)

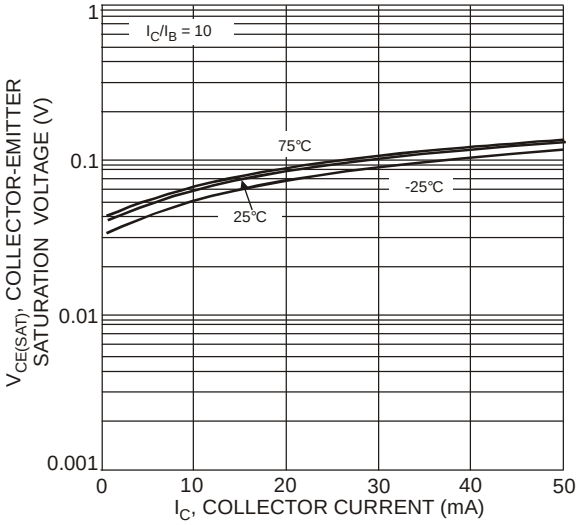


Fig. 2 Typical $V_{CE(SAT)}$ vs. I_C

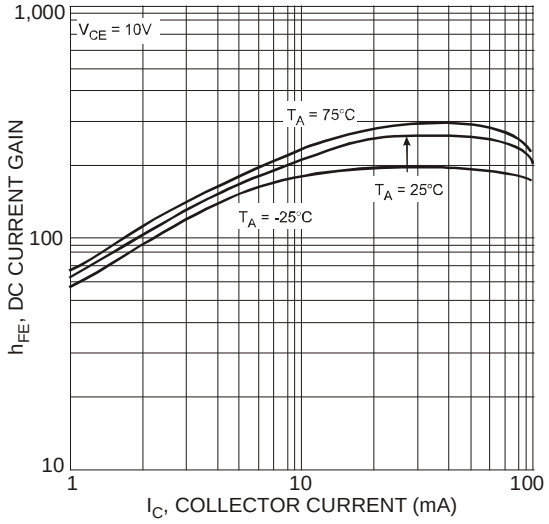


Fig. 3 Typical DC Current Gain

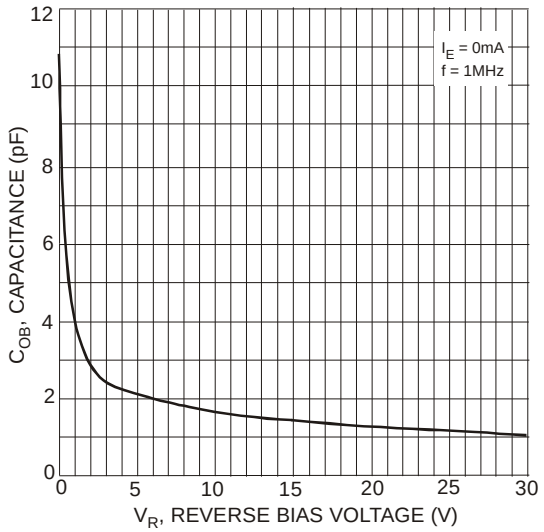


Fig. 4 Typical Output Capacitance

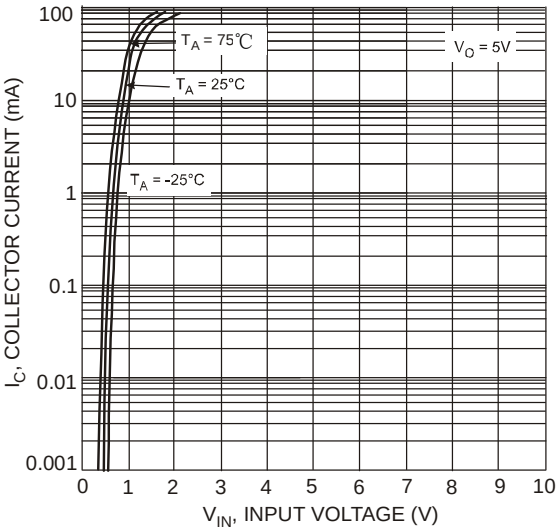


Fig. 5 Typical Collector Current vs. Input Voltage

Typical Curves – DCX123JU PNP Section (Cont.)

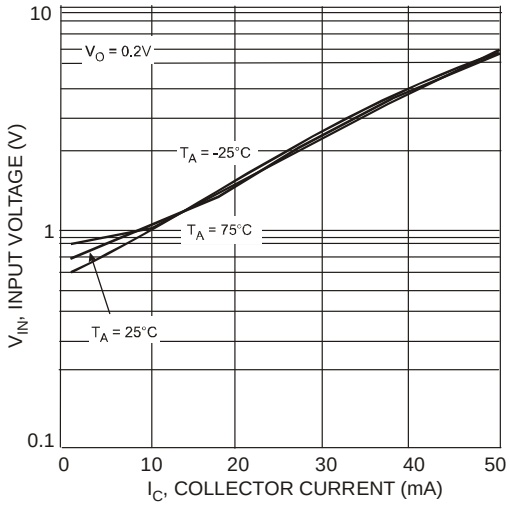


Fig. 6 Typical Input Voltage vs. Collector Current

Typical Curves – DCX123JU NPN Section (@T_A = +25°C, unless otherwise specified.)

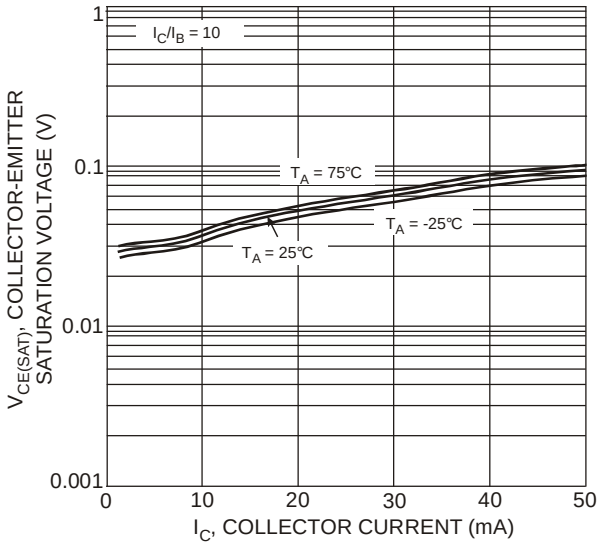


Fig. 7 Typical $V_{CE(SAT)}$ vs. I_C

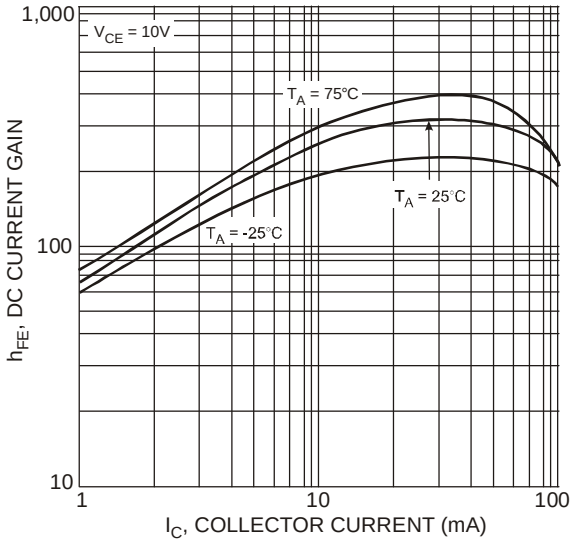


Fig. 8 Typical DC Current Gain

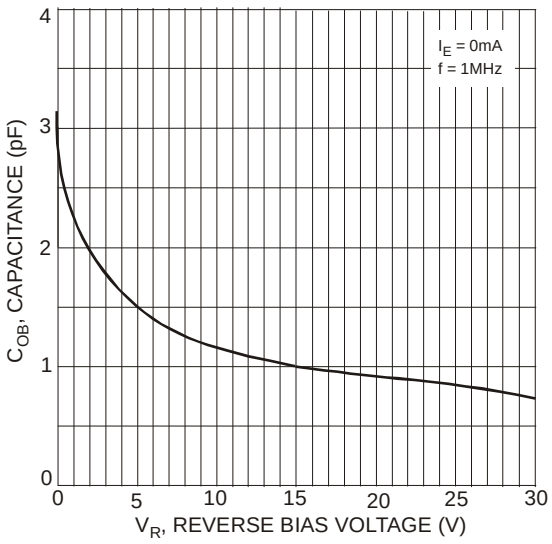


Fig. 9 Typical Output Capacitance

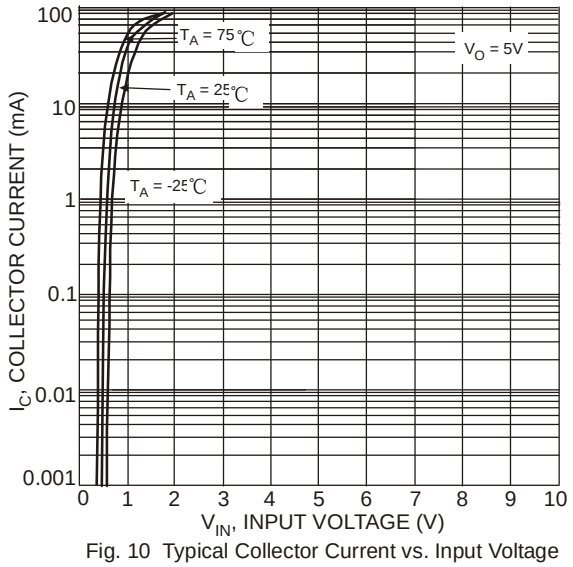


Fig. 10 Typical Collector Current vs. Input Voltage

Typical Curves – DCX123JU NPN Section (Cont.)

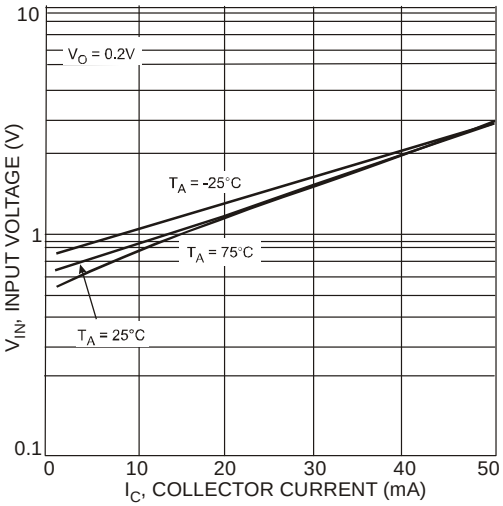


Fig. 11 Typical Input Voltage vs. Collector Current

Typical Curves – DCX143EU PNP Section (@T_A = +25°C, unless otherwise specified.)

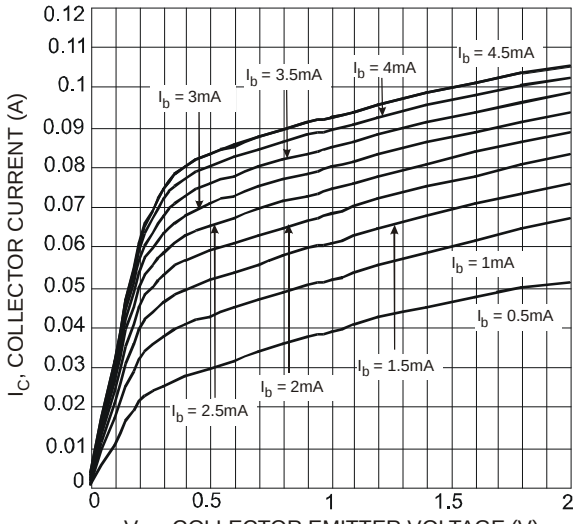


Fig. 12 Typical V_{CE} vs. I_C

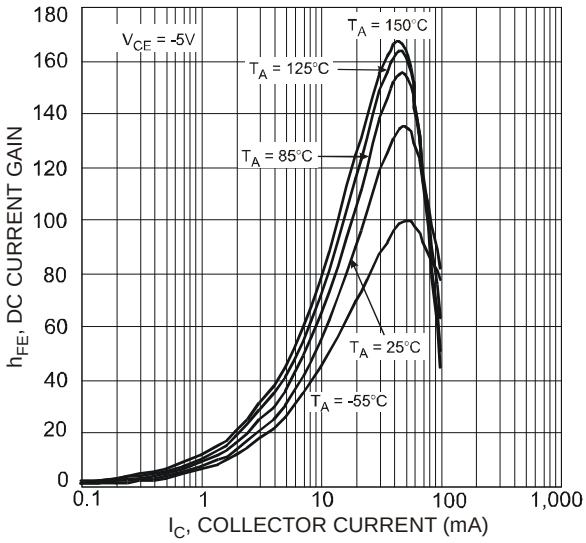


Fig. 13 Typical DC Current Gain

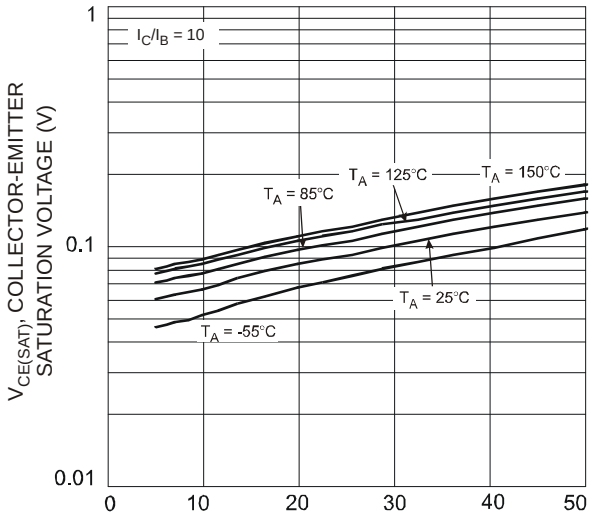


Fig. 14 Typical $V_{CE(SAT)}$ vs. I_C

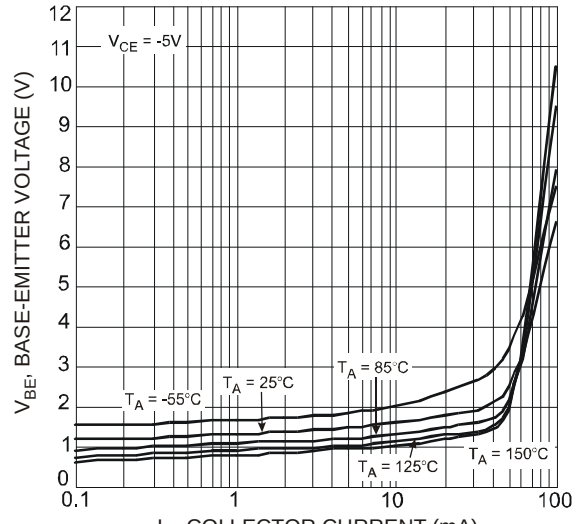


Fig. 15 Typical V_{BE} vs. I_C

Typical Curves – DCX143EU PNP Section (Cont.)

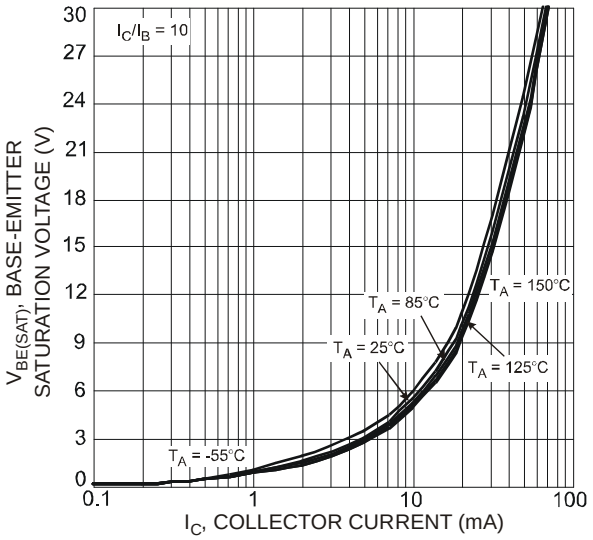


Fig. 16 Typical $V_{BE(SAT)}$ vs. I_C

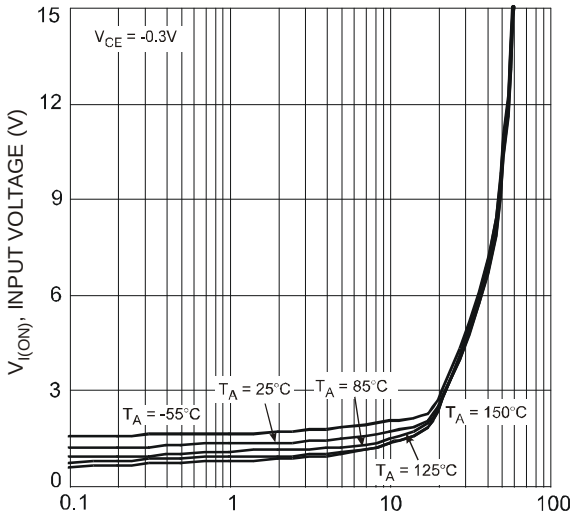


Fig. 17 Typical $V_{I(ON)}$ vs. I_C

Typical Curves – DCX143EU NPN Section (@T_A = +25°C, unless otherwise specified.)

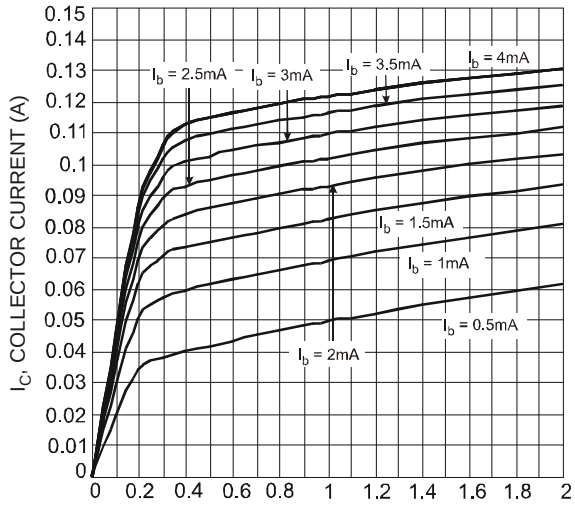


Fig. 18 Typical V_{CE} vs. I_C

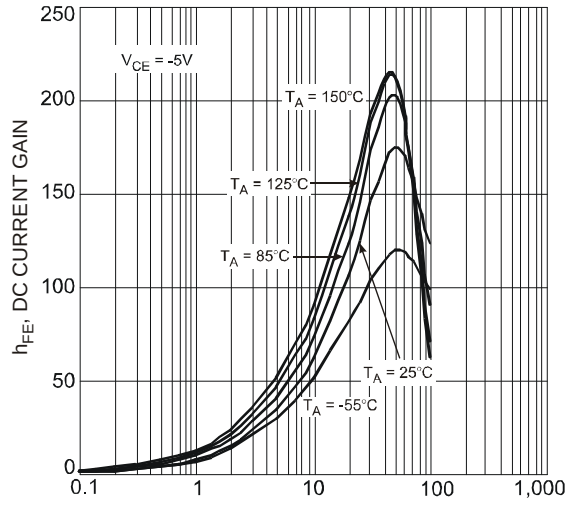


Fig. 19 Typical DC Current Gain

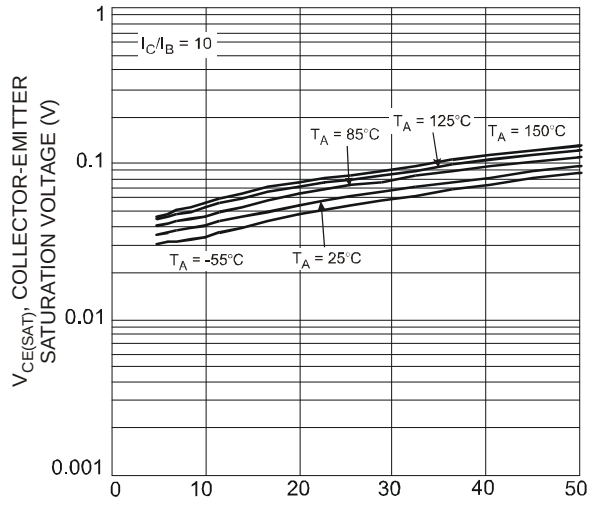


Fig. 20 Typical $V_{CE(SAT)}$ vs. I_C

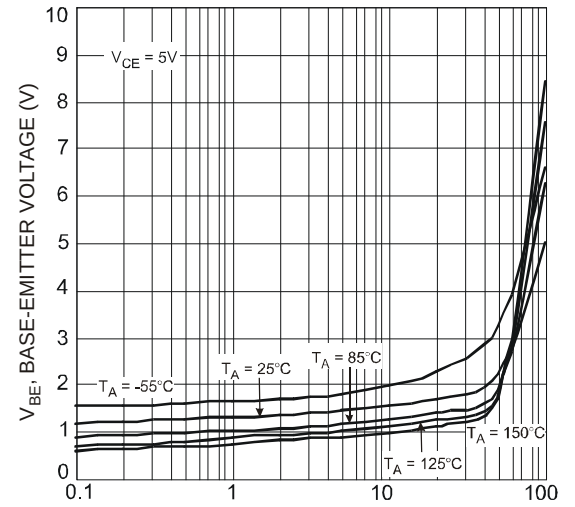


Fig. 21 Typical V_{BE} vs. I_C

Typical Curves – DCX143EU NPN Section (Cont.)

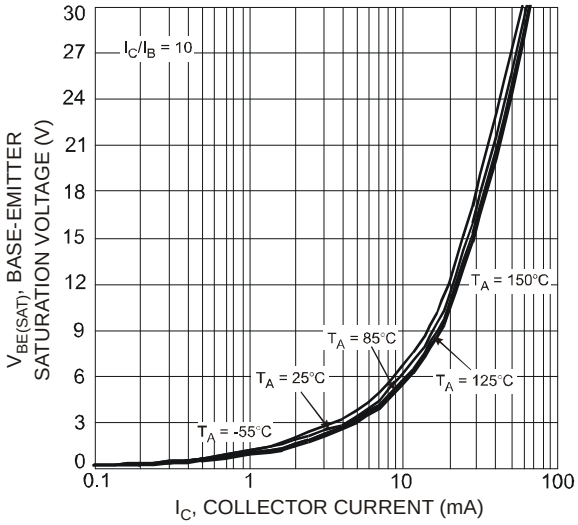


Fig. 22 Typical $V_{BE(SAT)}$ vs. I_C

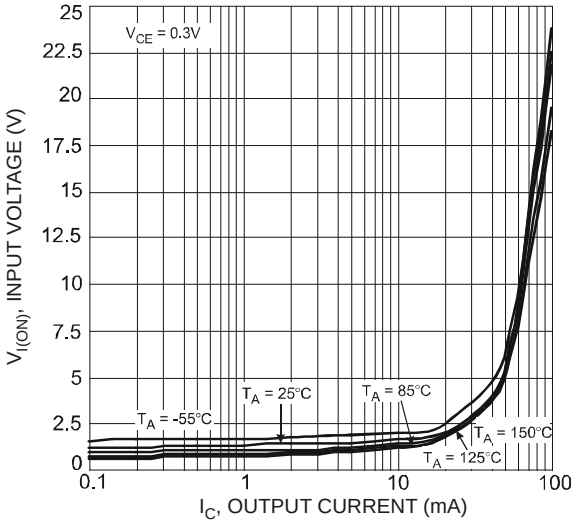


Fig. 23 Typical $V_{I(ON)}$ vs. I_C

Typical Curves – DCX114TU PNP Section (@T_A = +25°C, unless otherwise specified.)

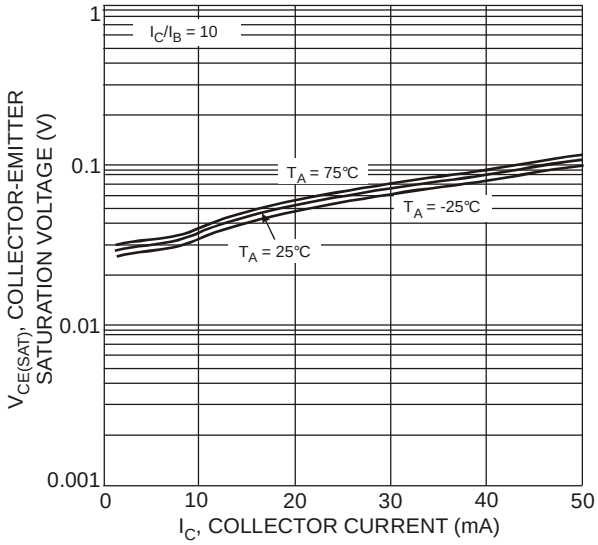


Fig. 24 Typical $V_{CE(SAT)}$ vs. I_C

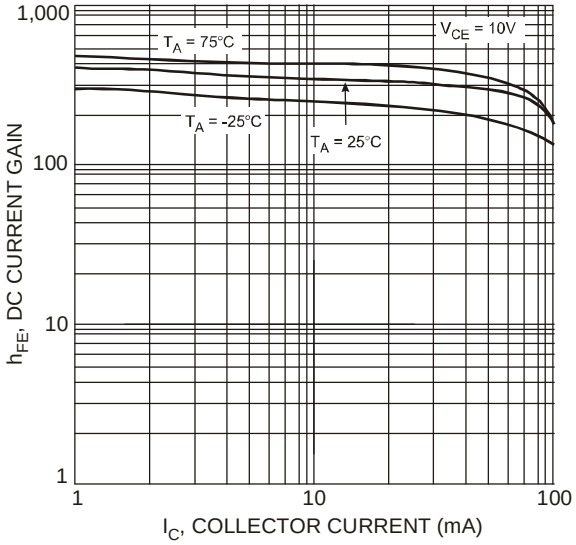


Fig. 25 Typical DC Current Gain

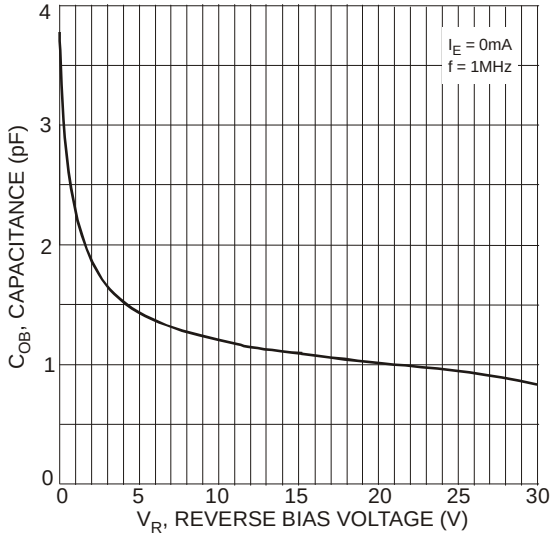


Fig. 26 Typical Output Capacitance

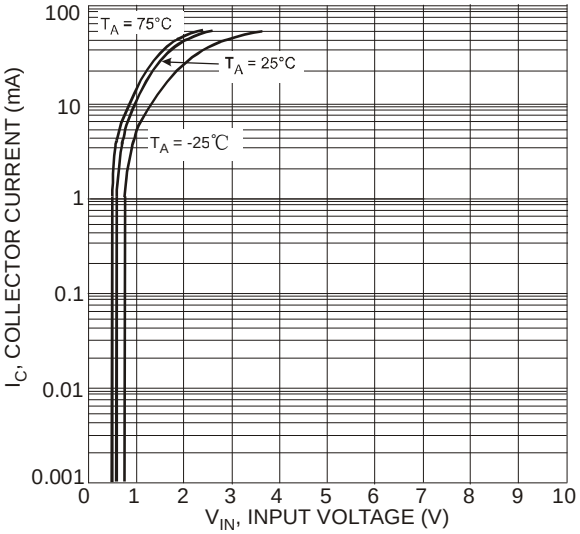


Fig. 27 Typical Collector Current vs. Input Voltage

Typical Curves – DCX114TU PNP Section (Cont.)

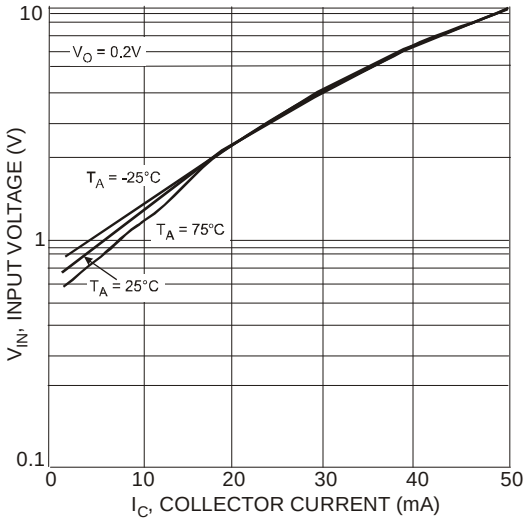


Fig. 28 Typical Input Voltage vs. Collector Current

Typical Curves – DCX114TU NPN Section (@T_A = +25°C, unless otherwise specified.)

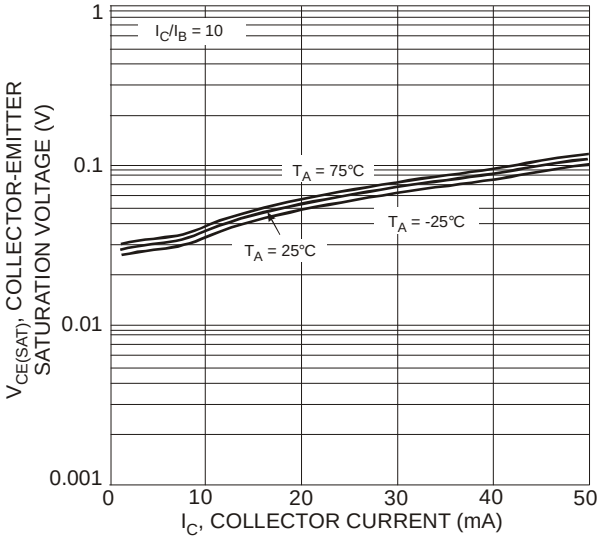


Fig. 29 Typical $V_{CE(SAT)}$ vs. I_C

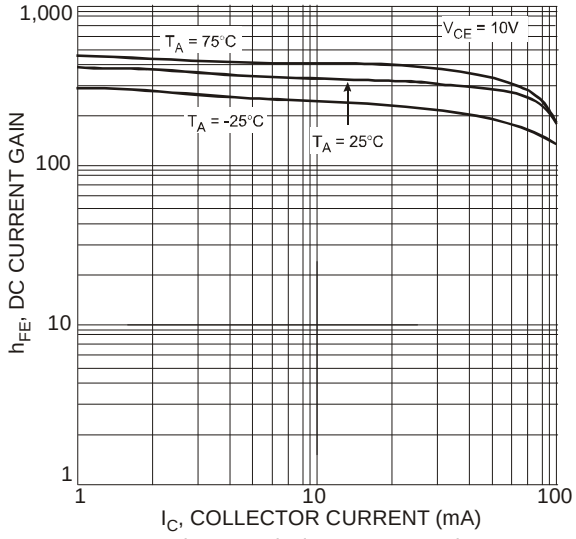


Fig. 30 Typical DC Current Gain

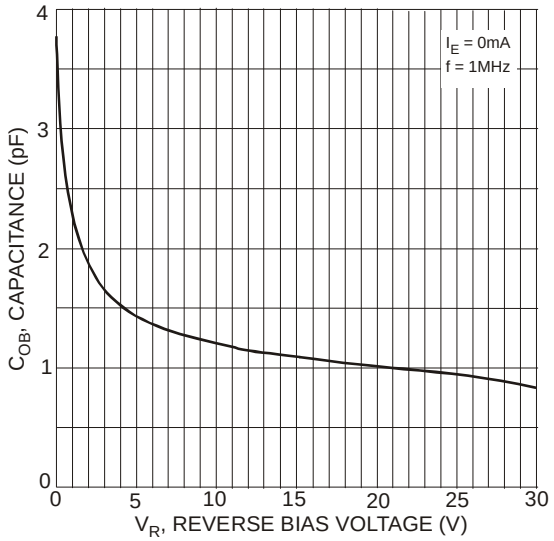


Fig. 31 Typical Output Capacitance

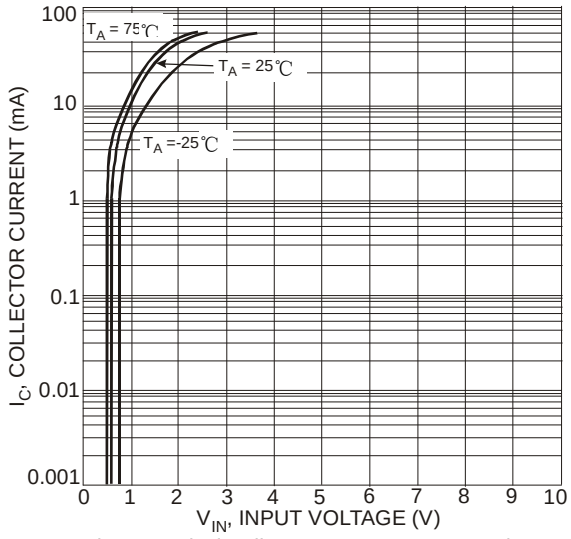


Fig. 32 Typical Collector Current vs. Input Voltage

Typical Curves – DCX114TU NPN Section (Cont.)

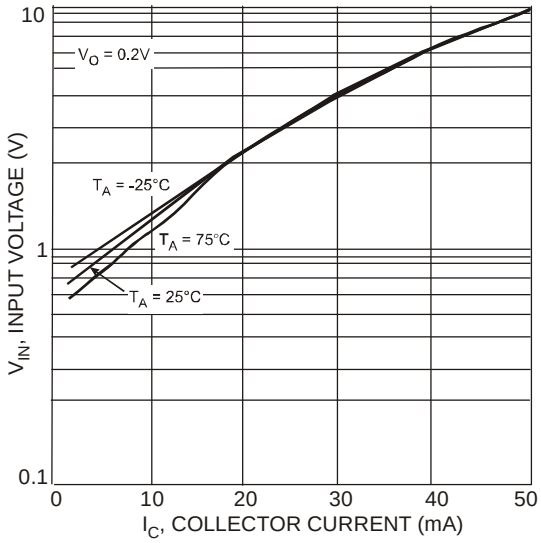
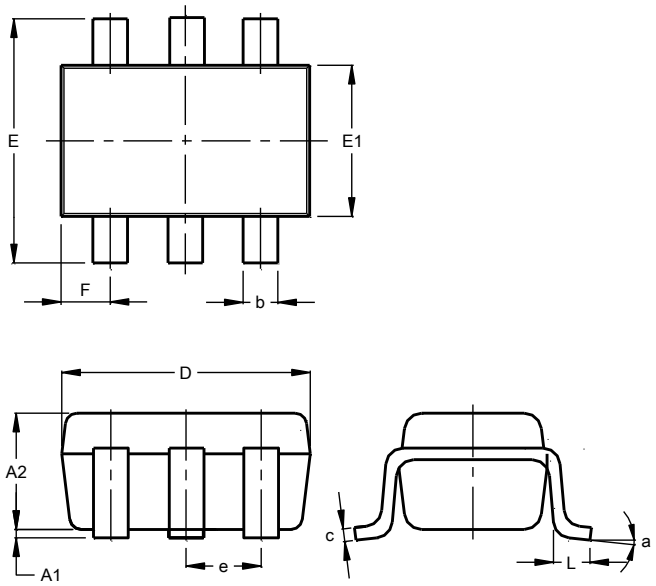


Fig. 33 Typical Input Voltage vs. Collector Current

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT363

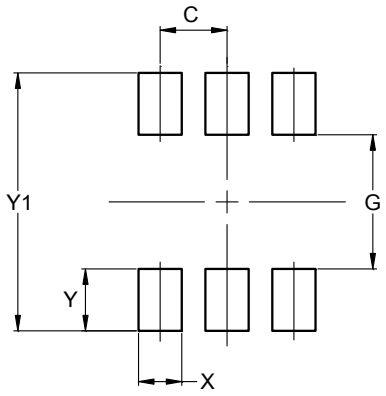


SOT363			
Dim	**Min**	**Max**	**Typ**
A1	0.00	0.10	0.05
A2	0.90	1.00	0.95
b	0.10	0.30	0.25
c	0.10	0.22	0.11
D	1.80	2.20	2.15
E	2.00	2.20	2.10
E1	1.15	1.35	1.30
e	0.650 BSC		
F	0.40	0.45	0.425
L	0.25	0.40	0.30
a	0°	8°	--
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT363



Dimensions	Value (in mm)
C	0.650
G	1.300
X	0.420
Y	0.600
Y1	2.500